



SD1275-01

RF POWER BIPOLAR TRANSISTORS VHF MOBILE APPLICATIONS

FEATURES SUMMARY

- 160 MHz
- 13.6 VOLTS
- COMMON EMITTER
- $P_{OUT} = 40\text{ W MIN. WITH } 9.0\text{ dB GAIN}$

DESCRIPTION

The SD1275-01 is a 13.6 V Class C epitaxial silicon NPN planar transistor designed primarily for VHF communications. The SD1275-01 utilizes an emitter ballasted die geometry to withstand severe load mismatch conditions.

Figure 1. Package

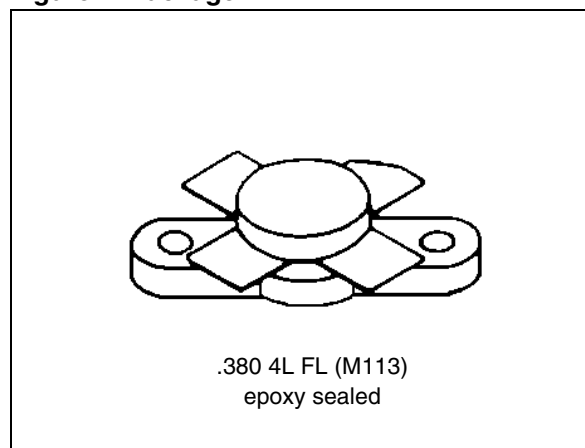


Figure 2. Pin Connection

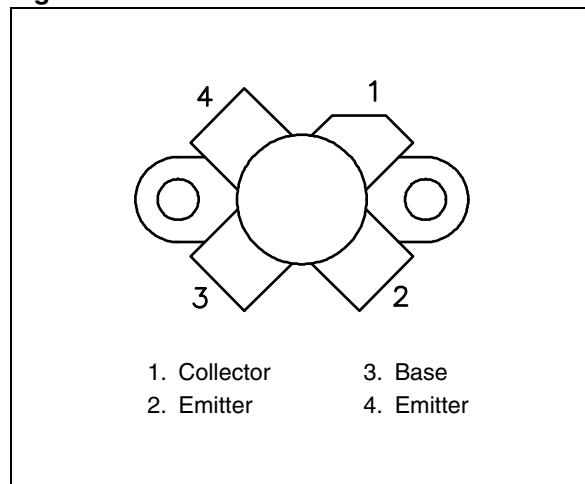


Table 1. Order Codes

Order Codes	Marking	Package	Packaging
SD1275-01	SD1275-1	M113	PLASTIC TRAYS

Table 2. Absolute Maximum Ratings ($T_{\text{case}} = 25^{\circ}\text{C}$)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	36	V
V_{CEO}	Collector-Emitter Voltage	16	V
V_{CES}	Collector-Emitter Voltage	36	V
V_{EBO}	Emitter-Base Voltage	4.0	V
I_{C}	Device Current	8.0	A
P_{DISS}	Power Dissipation	70	W
T_{J}	Junction Temperature	+200	$^{\circ}\text{C}$
T_{STG}	Storage Temperature	- 65 to +150	$^{\circ}\text{C}$

Table 3. Thermal Data

Symbol	Parameter	Value	Unit
$R_{\text{TH(j-c)}}$	Junction-Case Thermal Resistance	1.2	$^{\circ}\text{C/W}$

ELECTRICAL SPECIFICATIONS ($T_{\text{CASE}} = 25^{\circ}\text{C}$)**Table 4. Static**

Symbol	Test Conditions	Value			Unit
		Min.	Typ.	Max.	
BV_{CES}	$I_{\text{C}} = 15 \text{ mA}$; $V_{\text{BE}} = 0 \text{ mA}$	36	—	—	V
BV_{CEO}	$I_{\text{C}} = 50 \text{ mA}$; $I_{\text{B}} = 0 \text{ mA}$	16	—	—	V
BV_{EBO}	$I_{\text{E}} = 5 \text{ mA}$; $I_{\text{C}} = 0 \text{ mA}$	4.0	—	—	V
I_{CBO}	$V_{\text{CB}} = 15 \text{ V}$; $I_{\text{E}} = 0 \text{ mA}$	—	—	5	mA
h_{FE}	$V_{\text{CE}} = 5 \text{ V}$; $I_{\text{C}} = 250 \text{ mA}$	20	—	—	—

Table 5. Dynamic

Symbol	Test Conditions	Value			Unit
		Min.	Typ.	Max.	
P_{OUT}	$f = 160 \text{ MHz}$; $P_{\text{IN}} = 5.0 \text{ W}$; $V_{\text{CE}} = 13.6 \text{ V}$	40	—	—	W
G_{P}	$f = 160 \text{ MHz}$; $P_{\text{IN}} = 5.0 \text{ W}$; $V_{\text{CE}} = 13.6 \text{ V}$	9	—	—	dB
C_{OB}	$f = 1 \text{ MHz}$; $V_{\text{CB}} = 15 \text{ V}$	—	95	—	pF

TYPICAL PERFORMANCE

Figure 3. Power Gain vs Frequency

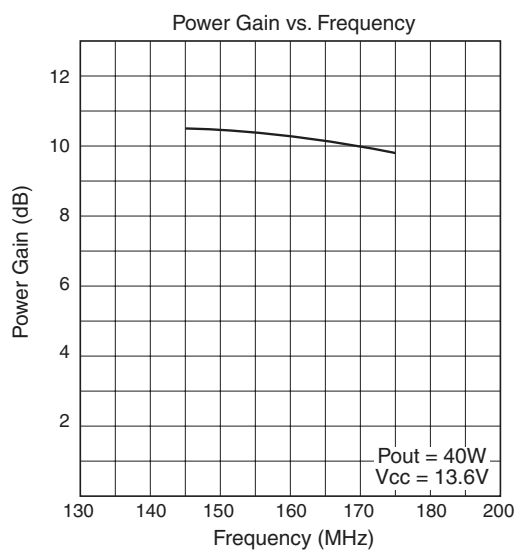


Figure 4. Power Output vs Power Input

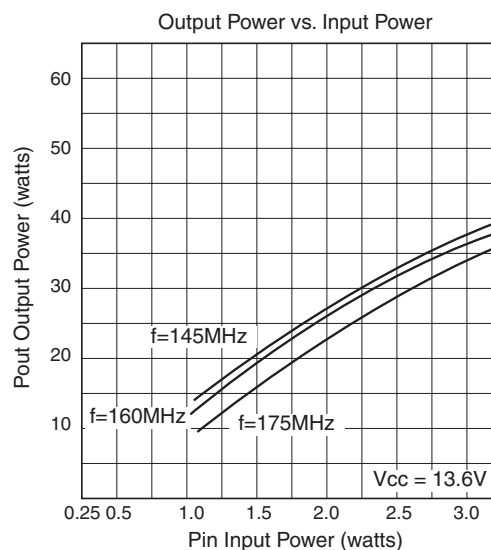


Figure 5. Power Output vs Supply Voltage (175 MHz)

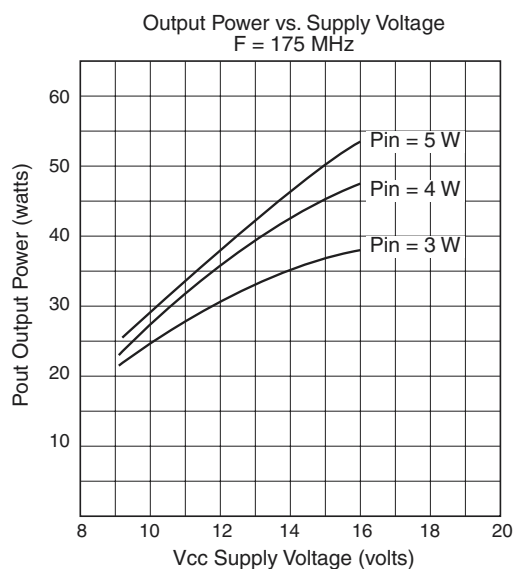


Figure 6. Power Output vs Supply Voltage (145 MHz)

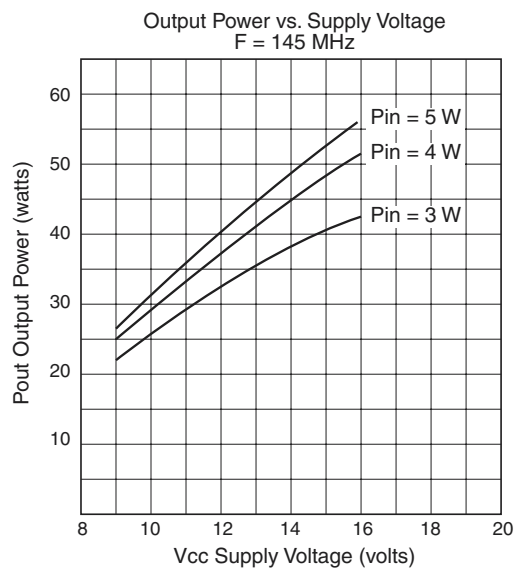


Figure 7. Power Output vs Supply Voltage
(160 MHz)

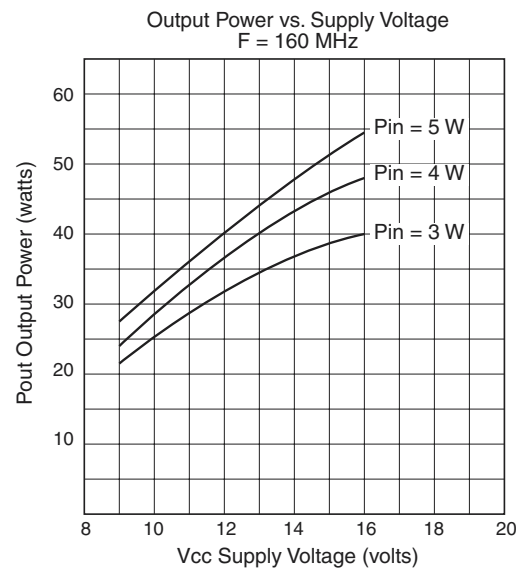


Table 6. Impedance Data ⁽¹⁾

FREQ.	Z _{IN} (Ω)	Z _{CL} (Ω)
160 MHz	1.0 + j 0.4	2.3 + j 0.1

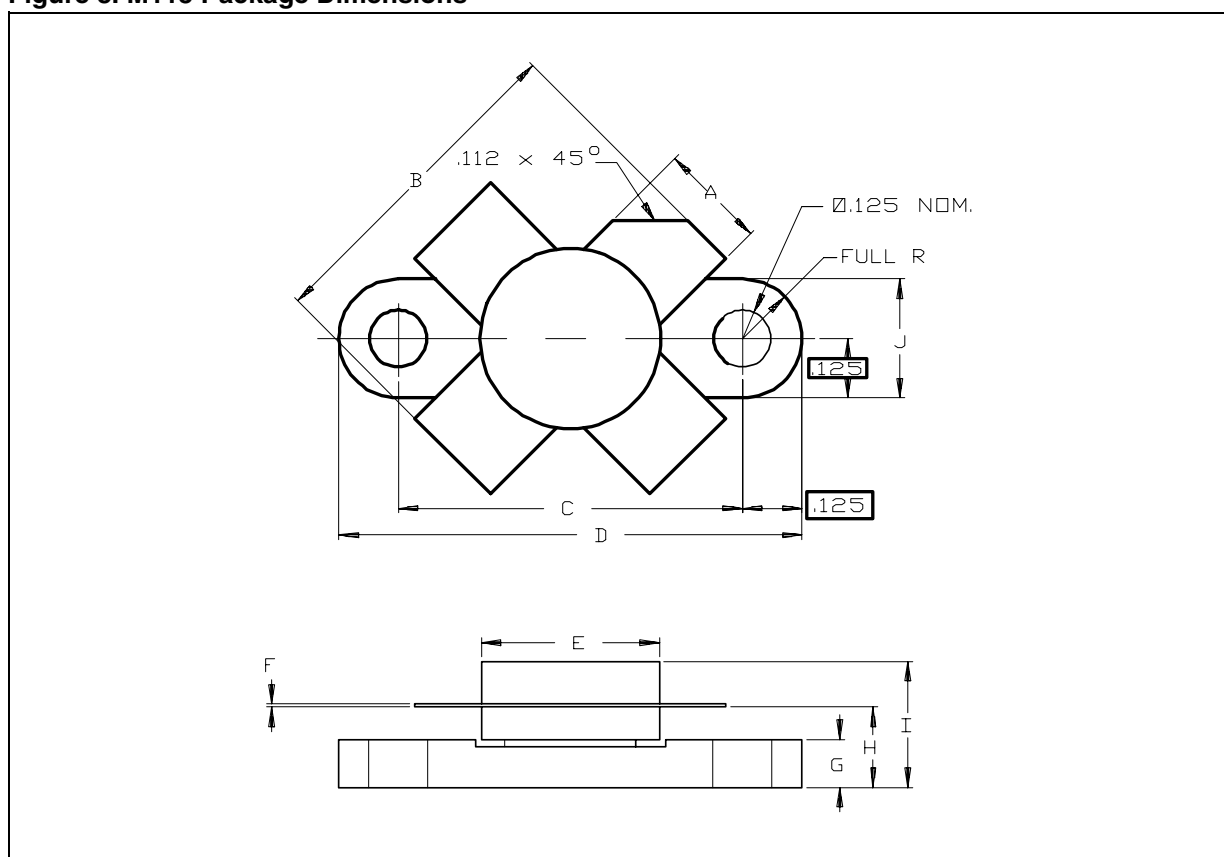
Note: 1. P_{IN} = 3.0 W; V_{CE} = 12.5 V

PACKAGE MECHANICAL

Table 7. M113 Mechanical Data

Symbol	millimeters			inches		
	Min	Typ	Max	Min	Typ	Max
A	5.59		5.84	0.220		0.230
B	19.94			0.785		
C	18.29		18.54	0.720		0.730
D	24.64		24.89	0.970		0.980
E			9.78			0.385
F	0.10		0.15	0.004		0.006
G	2.16		2.67	0.085		0.105
H	4.06		4.57	0.160		0.180
I			7.11			0.280
J	6.10		6.48	0.240		0.255

Figure 8. M113 Package Dimensions



Note: Drawing is not to scale.

REVISION HISTORY

Table 8. Revision History

Date	Revision	Description of Changes
June-1993	1	First Issue
25-May-2004	2	Stylesheet update. No content change.

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